

**DUAL 30V N-CHANNEL ENHANCEMENT MODE MOSFET**
**Product Summary**

$V_{(BR)DSS}$	$R_{DS(ON)}$	Package	$I_D$ $T_A = +25^\circ\text{C}$ (Notes 5 & 6)
30V	135m $\Omega$ @ $V_{GS} = 10\text{V}$	MSOP-8	2.3A
	200m $\Omega$ @ $V_{GS} = 4.5\text{V}$		1.9A

**Description**

This MOSFET has been designed to minimize the on-state resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

**Applications**

- DC-DC Converters
- Power Management Functions
- Motor Control
- Disconnect Switches

**Features**

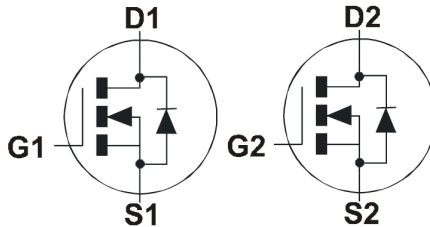
- Low On-Resistance
- Low Threshold
- Fast Switching Speed
- Low Gate Drive
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

**Mechanical Data**

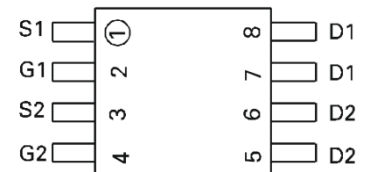
- Case: MSOP-8
- Case Material: Molded Plastic, "Green" Molding Compound.  
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish  $\text{③}$
- Weight: 0.008 grams (approximate)



Top View



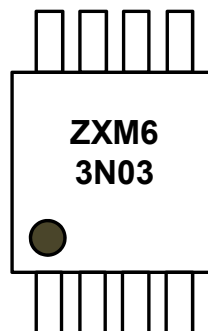
Device Symbol


 Top View  
Pin-Out

**Ordering Information** (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXMD63N03XTA	ZXM63N03	7	12	1,000
ZXMD63N03XTC	ZXM63N03	13	12	4,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

**Marking Information**


ZXM63N03 = Product type Marking Code

**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

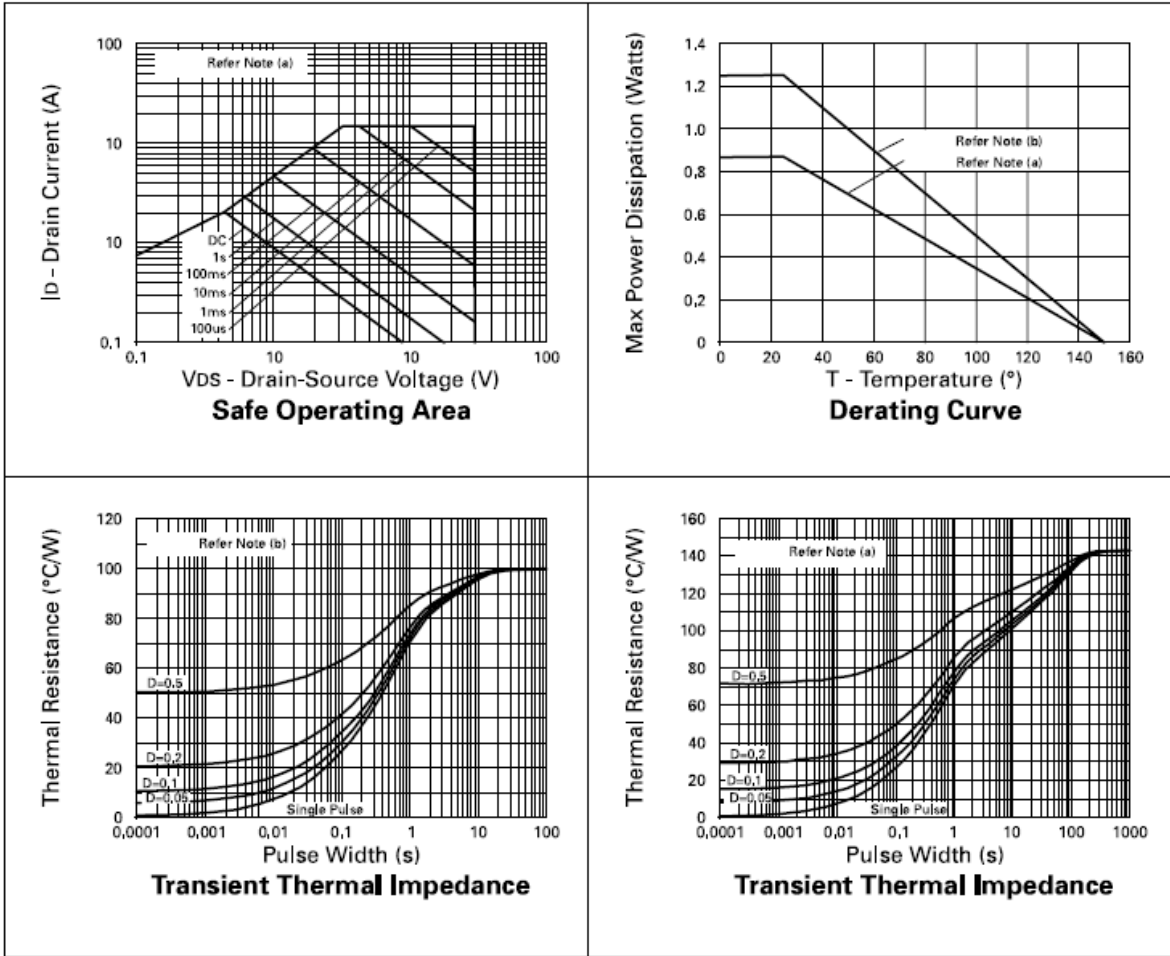
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	30	V
Gate-Source Voltage			V <sub>GSS</sub>	±20	V
Continuous Drain Current	Steady State	@ V <sub>GS</sub> = 4.5V; T <sub>A</sub> = +25°C (Note 5 & 6)	I <sub>D</sub>	2.3	A
		@ V <sub>GS</sub> = 4.5V; T <sub>A</sub> = +70°C (Note 5 & 6)		1.8	
Pulsed Drain Current		(Notes 6 & 7)	I <sub>DM</sub>	14	A
Continuous Source Current (Body Diode)		(Notes 5 & 6)	I <sub>S</sub>	1.5	A
Pulsed Source Current (Body Diode)		(Notes 6 & 7)	I <sub>SM</sub>	14	A

**Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Power Dissipation	(Notes 6 & 8)	P <sub>D</sub>	0.87	W
	(Notes 5 & 6)		1.25	
	(Notes 8 & 9)		1.04	
Thermal Resistance, Junction to Ambient	(Notes 6 & 8)	R <sub>θJA</sub>	143	°C/W
	(Notes 5 & 6)		100	
	(Notes 8 & 9)		120	
Thermal Resistance, Junction to Leads	(Note 10)	R <sub>θJL</sub>	84.9	°C/W
Operating and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

- Notes:
5. For a device surface mounted on FR4 PCB measured at t ≤ 10 sec.
  6. For device with one active die.
  7. Repetitive rating - 25mm x 25mm FR4 PCB, D = 0.02, pulse width 300µs – pulse width limited by maximum junction temperature.
  8. For a device surface mounted on 25mm x 25mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
  9. For device with two active die running at equal power.
  10. Thermal resistance from junction to solder-point (at the end of the drain lead).

**Thermal Characteristics**

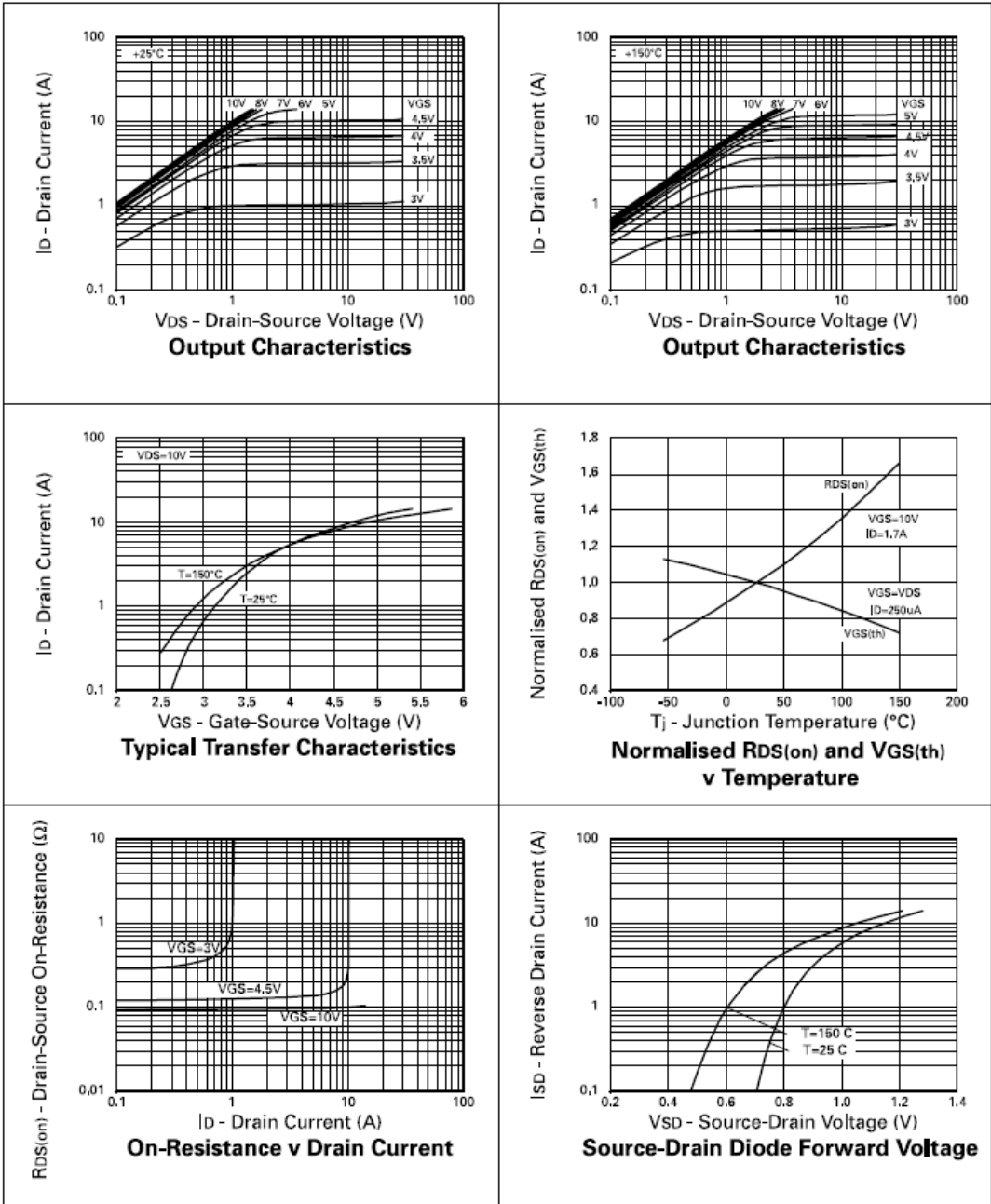


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

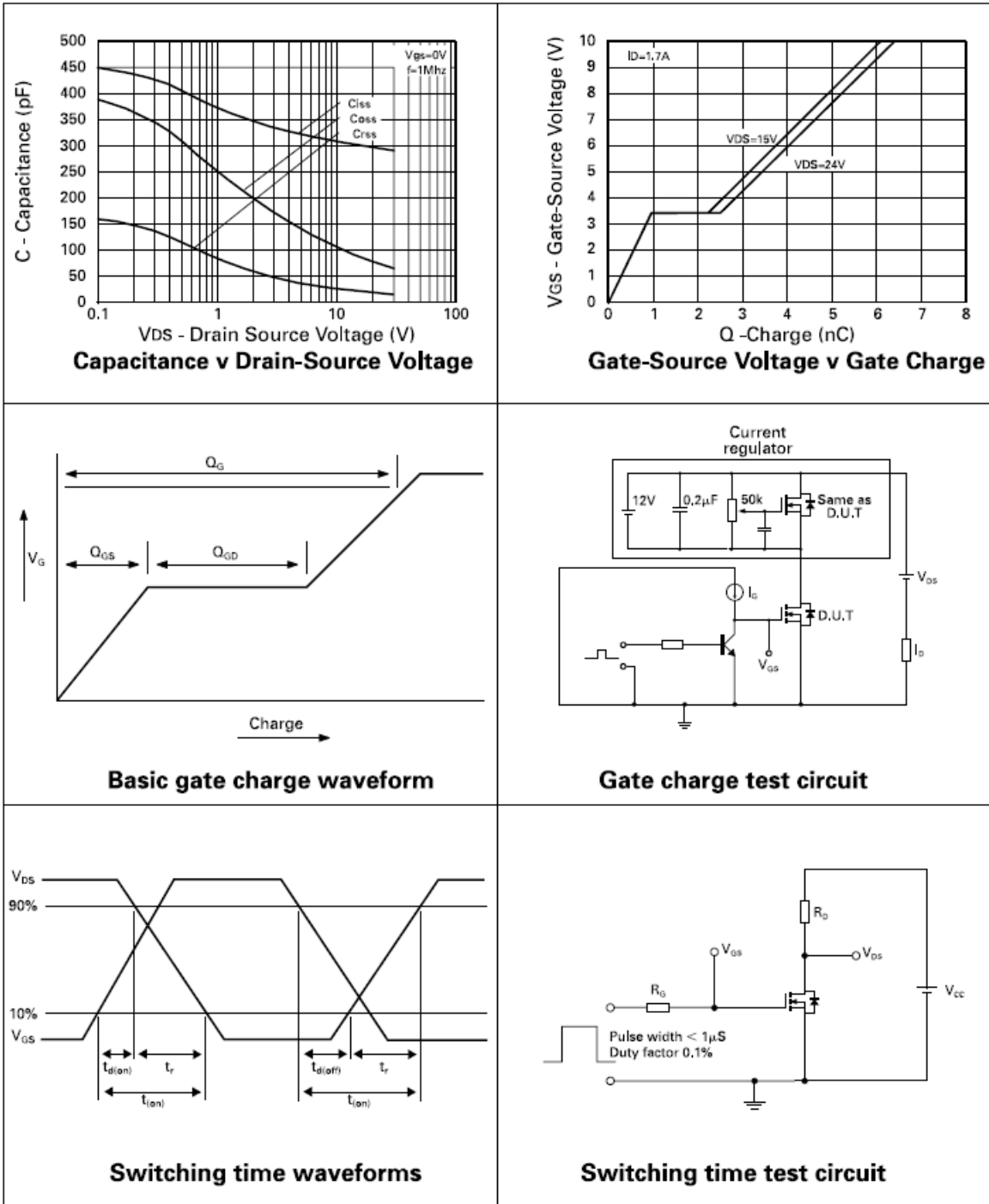
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	—	—	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	—	—	1.0	μA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	—	—	100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0	—	—	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250μA
Static Drain-Source On-Resistance (Note 11)	R <sub>DS(on)</sub>	—	—	135	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 1.7A
				200		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 0.85A
Forward Transconductance (Notes 11 & 13)	g <sub>fs</sub>	1.9	—	—	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 0.85A
Diodes Forward Voltage (Note 11)	V <sub>SD</sub>	—	—	0.95	V	T <sub>J</sub> = 25°C, I <sub>S</sub> = 1.7A, V <sub>GS</sub> = 0V
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance (Note 12 & 13)	C <sub>iss</sub>	—	290	—	pF	V <sub>DS</sub> = 25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Output Capacitance (Notes 12 & 13)	C <sub>oss</sub>	—	70	—		
Reverse Transfer Capacitance (Notes 12 & 13)	C <sub>rss</sub>	—	20	—		
Total Gate Charge (Notes 12 & 13)	Q <sub>g</sub>	—	—	8	nC	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 24V, I <sub>D</sub> = 1.7A
Gate-Source Charge (Notes 12 & 13)	Q <sub>gs</sub>	—	—	1.2		
Gate-Drain Charge (Notes 12 & 13)	Q <sub>gd</sub>	—	—	2		
Reverse Recovery Time (Note 13)	t <sub>rr</sub>	—	16.9	—	ns	T <sub>J</sub> = +25°C, I <sub>F</sub> = 1.7A, di/dt = 100A/μs
Reverse Recovery Charge (Note 13)	Q <sub>rr</sub>	—	9.5	—	nC	
Turn-On Delay Time (Notes 12 & 13)	t <sub>D(on)</sub>	—	2.5	—	ns	V <sub>DD</sub> = 15V, I <sub>D</sub> = 1.7A, R <sub>G</sub> = 6.1Ω, R <sub>D</sub> = 8.7Ω,
Turn-On Rise Time (Notes 12 & 13)	t <sub>r</sub>	—	4.1	—		
Turn-Off Delay Time (Notes 12 & 13)	t <sub>D(off)</sub>	—	9.6	—		
Turn-Off Fall Time (Notes 12 & 13)	t <sub>f</sub>	—	4.4	—		

- Notes:
11. Measured under pulsed conditions. Pulse width ≤ 300μs; duty cycle ≤ 2%.
  12. Switching characteristics are independent of operating junction temperature.
  13. For design aid only, not subject to production testing.

**Typical Characteristics**

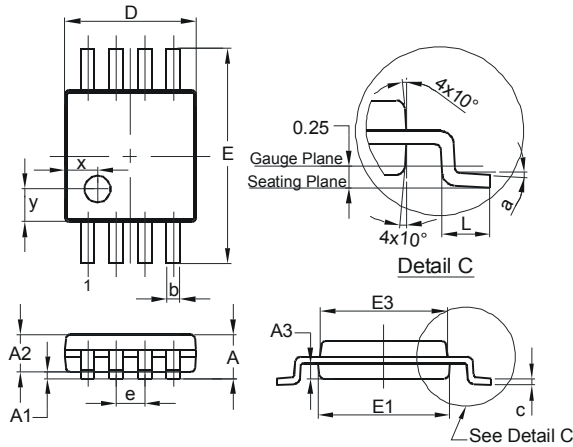


**Typical Characteristics (cont.)**



**Package Outline Dimensions**

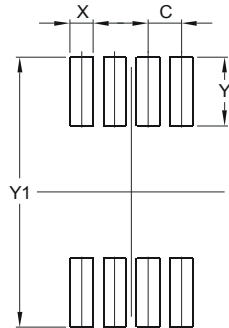
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



MSOP-8			
Dim	Min	Max	Typ
A	-	1.10	-
A1	0.05	0.15	0.10
A2	0.75	0.95	0.86
A3	0.29	0.49	0.39
b	0.22	0.38	0.30
c	0.08	0.23	0.15
D	2.90	3.10	3.00
E	4.70	5.10	4.90
E1	2.90	3.10	3.00
E3	2.85	3.05	2.95
e	-	-	0.65
L	0.40	0.80	0.60
a	0°	8°	4°
x	-	-	0.750
y	-	-	0.750
<b>All Dimensions in mm</b>			

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for latest version.



Dimensions	Value (in mm)
C	0.650
X	0.450
Y	1.350
Y1	5.300

**IMPORTANT NOTICE**

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

**LIFE SUPPORT**

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2014, Diodes Incorporated

[www.diodes.com](http://www.diodes.com)